

DATA SHEET

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74AHC245; 74AHCT245 Octal bus transceiver; 3-state

Product specification
Supersedes data of 1998 Sep 21
File under Integrated Circuits, IC06

1999 Sep 28

Octal bus transceiver; 3-state

74AHC245; 74AHCT245

FEATURES

- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V
CDM EIA/JESD22-C101 exceeds 1000 V
- Balanced propagation delays
- All inputs have a Schmitt-trigger action
- Inputs accepts voltages higher than V_{CC}
- For AHC only:
operates with CMOS input levels
- For AHCT only:
operates with TTL input levels
- Specified from
-40 to +85 and +125 °C.

DESCRIPTION

The 74AHC/AHCT245 is a high-speed Si-gate CMOS device.

The 74AHC/AHCT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions.

The 74AHC245/74AHCT245 features an Output Enable (\overline{OE}) input for easy cascading and a send/receive (DIR) input for direction control.

\overline{OE} controls the outputs so that the buses are effectively isolated.

FUNCTION TABLE

See Note 1.

INPUTS		INPUTS/OUTPUTS	
\overline{OE}	DIR	A_n	B_n
L	L	A = B	inputs
L	H	inputs	B = A
H	X	Z	Z

Note

1. H = HIGH voltage level;
L = LOW voltage level;
X = don't care;
Z = high-impedance OFF-state.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25\text{ °C}$; $t_r = t_f \leq 3.0\text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			AHC	AHCT	
t_{PHL}/t_{PLH}	propagation delay A_n to B_n , B_n to A_n	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	3.5	5.0	ns
C_I	input capacitance	$V_I = V_{CC}$ or GND	3.5	3.5	pF
C_O	output capacitance		4.0	4.0	pF
C_{PD}	power dissipation capacitance	$C_L = 50\text{ pF}$; $f = 1\text{ MHz}$; notes 1 and 2	12	15	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs;
 C_L = output load capacitance in pF;
 V_{CC} = supply voltage in Volts.
2. The condition is $V_I = \text{GND}$ to V_{CC} .

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ORDERING INFORMATION

OUTSIDE NORTH AMERICA	NORTH AMERICA	PACKAGES			
		PINS	PACKAGE	MATERIAL	CODE
74AHC245D	74AHC245D	20	SO	plastic	SOT163-1
74AHC245PW	74AHC245PW DH	20	TSSOP	plastic	SOT360-1
74AHCT245D	74AHCT245D	20	SO	plastic	SOT163-1
74AHCT245PW	74AHCT245PW DH	20	TSSOP	plastic	SOT360-1

PINNING

PIN	SYMBOL	DESCRIPTION
1	DIR	direction control
2 to 9	A ₀ to A ₇	data inputs/outputs
10	GND	ground (0 V)
11 to 18	B ₇ to B ₀	data inputs/outputs
19	\overline{OE}	output enable input (active LOW)
20	V _{CC}	DC supply voltage

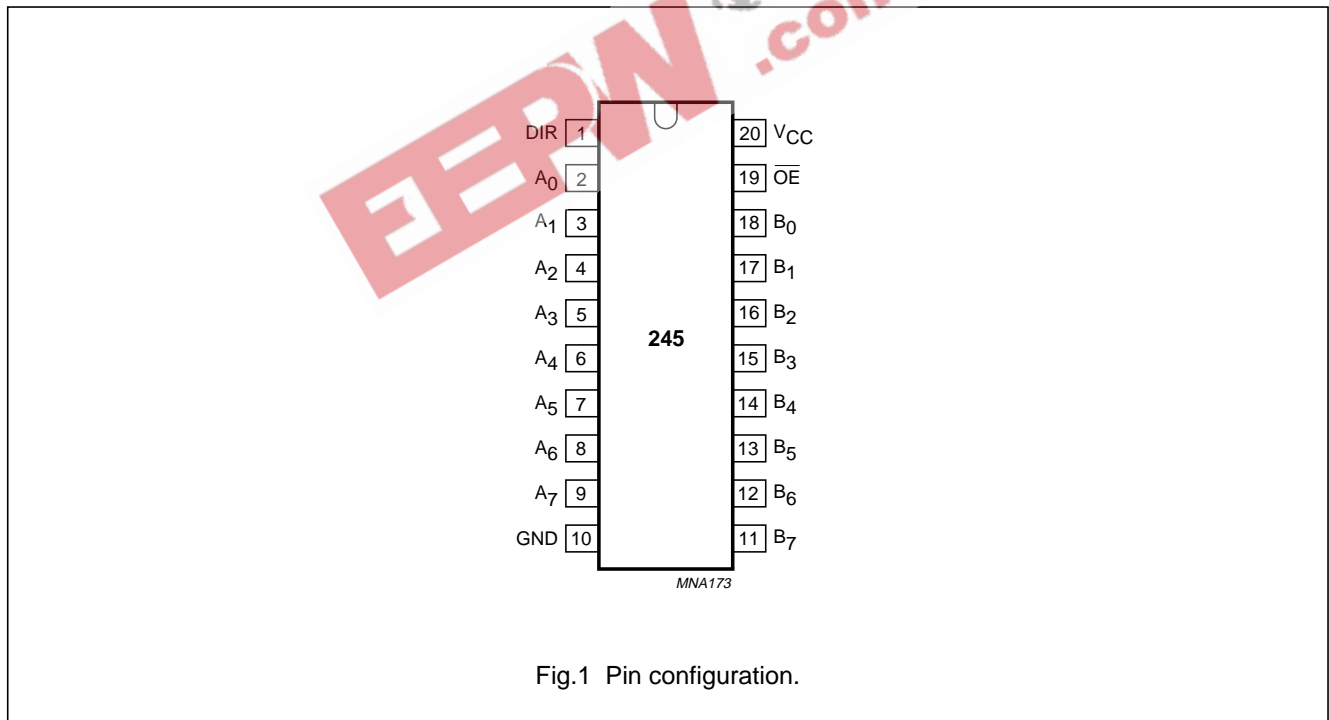


Fig.1 Pin configuration.

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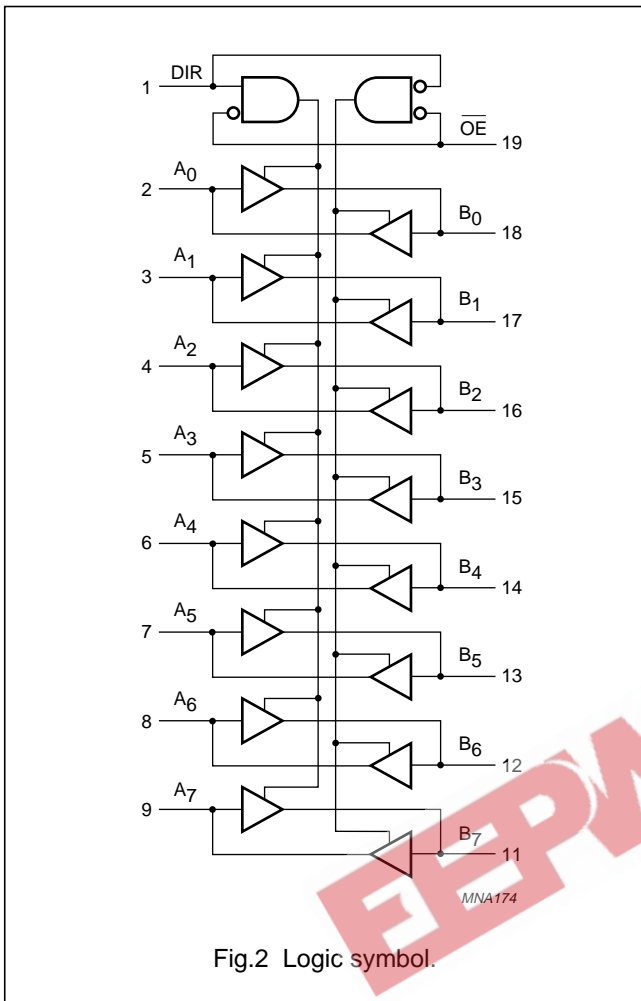


Fig.2 Logic symbol.

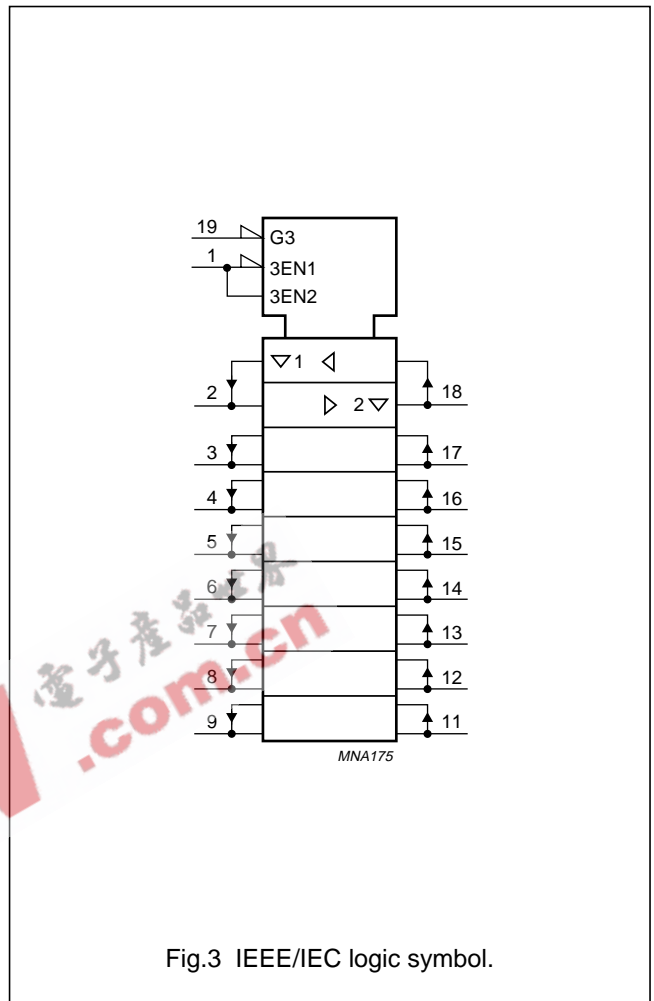


Fig.3 IEEE/IEC logic symbol.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74AHC			74AHCT			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V_{CC}	DC supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
V_I	input voltage		0	–	5.5	0	–	5.5	V
V_O	output voltage		0	–	V_{CC}	0	–	V_{CC}	V
T_{amb}	operating ambient temperature range	see DC and AC characteristics per device	–40	+25	+85	–40	+25	+85	°C
			–40	+25	+125	–40	+25	+125	°C
t_r, t_f ($\Delta t/\Delta f$)	input rise and fall rates	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$	–	–	100	–	–	–	ns/V
		$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$	–	–	20	–	–	20	

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	DC supply voltage		–0.5	+7.0	V
V_I	input voltage range		–0.5	+7.0	V
I_{IK}	DC input diode current	$V_I < -0.5\text{ V}$; note 1	–	–20	mA
I_{OK}	DC output diode current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$; note 1	–	± 20	mA
I_O	DC output source or sink current	$-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$	–	± 25	mA
I_{CC}	DC V_{CC} or GND current		–	± 75	mA
T_{stg}	storage temperature range		–65	+150	°C
P_D	power dissipation per package	for temperature range: –40 to +125 °C; note 2	–	500	mW

Notes

- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SO packages: above 70 °C the value of P_D derates linearly with 8 mW/K.
For TSSOP packages: above 60 °C the value of P_D derates linearly with 5.5 mW/K.

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DC CHARACTERISTICS

74AHC family

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T_{amb} (°C)						UNIT	
		OTHER	V_{CC} (V)	25			-40 to +85		-40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.		MAX.
V_{IH}	HIGH-level input voltage		2.0	1.5	–	–	1.5	–	1.5	–	V
			3.0	2.1	–	–	2.1	–	2.1	–	
			5.5	3.85	–	–	3.85	–	3.85	–	
V_{IL}	LOW-level input voltage		2.0	–	–	0.5	–	0.5	–	0.5	V
			3.0	–	–	0.9	–	0.9	–	0.9	
			5.5	–	–	1.65	–	1.65	–	1.65	
V_{OH}	HIGH-level output voltage; all outputs	$V_I = V_{IH}$ or V_{IL} ; $I_O = -50 \mu A$	2.0	1.9	2.0	–	1.9	–	1.9	–	V
			3.0	2.9	3.0	–	2.9	–	2.9	–	
			4.5	4.4	4.5	–	4.4	–	4.4	–	
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $I_O = -4.0 \text{ mA}$	3.0	2.58	–	–	2.48	–	2.40	–	V
		$V_I = V_{IH}$ or V_{IL} ; $I_O = -8.0 \text{ mA}$	4.5	3.94	–	–	3.8	–	3.70	–	
V_{OL}	LOW-level output voltage; all outputs	$V_I = V_{IH}$ or V_{IL} ; $I_O = 50 \mu A$	2.0	–	0	0.1	–	0.1	–	0.1	V
			3.0	–	0	0.1	–	0.1	–	0.1	
			4.5	–	0	0.1	–	0.1	–	0.1	
	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $I_O = 4 \text{ mA}$	3.0	–	–	0.36	–	0.44	–	0.55	V
		$V_I = V_{IH}$ or V_{IL} ; $I_O = 8 \text{ mA}$	4.5	–	–	0.36	–	0.44	–	0.55	
I_I	input leakage current	$V_I = V_{CC}$ or GND	5.5	–	–	0.1	–	1.0	–	2.0	μA
I_{OZ}	3-state output OFF current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND	5.5	–	–	± 0.25	–	± 2.5	–	± 10.0	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	–	–	4.0	–	40	–	80	μA
C_I	input capacitance		–	–	3	10	–	10	–	10	pF

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74AHCT family

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)						UNIT	
		OTHER	V _{CC} (V)	25			-40 to +85		-40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.		MAX.
V _{IH}	HIGH-level input voltage		4.5 to 5.5	2.0	–	–	2.0	–	2.0	–	V
V _{IL}	LOW-level input voltage		4.5 to 5.5	–	–	0.8	–	0.8	–	0.8	V
V _{OH}	HIGH-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = -50 μA	4.5	4.4	4.5	–	4.4	–	4.4	–	V
	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = -8.0 mA	4.5	3.94	–	–	3.8	–	3.70	–	V
V _{OL}	LOW-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = 50 μA	4.5	–	0	0.1	–	0.1	–	0.1	V
	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = 8 mA	4.5	–	–	0.36	–	0.44	–	0.55	V
I _I	input leakage current	V _I = V _{IH} or V _{IL}	5.5	–	–	0.1	–	1.0	–	2.0	μA
I _{oz}	3-state output OFF current	V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND per input pin; other inputs at V _{CC} or GND; I _O = 0	5.5	–	–	±0.25	–	±2.5	–	±10.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	4.0	–	40	–	80	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} - 2.1 V other inputs at V _{CC} or GND; I _O = 0	4.5 to 5.5	–	–	1.35	–	1.5	–	1.5	mA
C _I	input capacitance		–	–	3	10	–	10	–	10	pF

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AC CHARACTERISTICS

Type 74AHC245

GND = 0 V; $t_r = t_f \leq 3.0$ ns.

SYMBOL	PARAMETER	TEST CONDITIONS		T_{amb} (°C)						UNIT	
		WAVEFORMS	C_L	25			-40 to +85		-40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.		MAX.
$V_{CC} = 3.0$ to 3.6 V; note 1											
t_{PHL}/t_{PLH}	propagation delay A_n to B_n ; B_n to A_n	see Figs 4 and 6	15 pF	–	5.0	8.4	1.0	10.0	1.0	10.5	ns
t_{PZL}/t_{PZH}	propagation delay \overline{OE} to A_n ; \overline{OE} to B_n ; signal name DIR	see Figs 5 and 6		–	6.5	13.2	1.0	15.5	1.0	16.5	ns
t_{PLZ}/t_{PHZ}	propagation delay \overline{OE} to A_n ; \overline{OE} to B_n ; signal name DIR			–	7.5	12.5	1.0	15.5	1.0	16.0	ns
t_{PHL}/t_{PLH}	propagation delay A_n to B_n ; B_n to A_n	see Figs 4 and 6	50 pF	–	6.5	11.9	1.0	13.5	1.0	15.0	ns
t_{PZL}/t_{PZH}	propagation delay \overline{OE} to A_n ; \overline{OE} to B_n ; signal name DIR	see Figs 5 and 6		–	9.0	16.7	1.0	19.0	1.0	21.0	ns
t_{PLZ}/t_{PHZ}	propagation delay \overline{OE} to A_n ; \overline{OE} to B_n ; signal name DIR			–	10.0	15.8	1.0	18.0	1.0	20.0	ns

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SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)						UNIT	
		WAVEFORMS	C _L	25			-40 to +85		-40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.		MAX.
V_{CC} = 4.5 to 5.5 V; note 2											
t _{PHL} /t _{PLH}	propagation delay A _n to B _n ; B _n to A _n	see Figs 4 and 6	15 pF	–	3.5	5.5	1.0	6.5	1.0	7.0	ns
t _{PZL} /t _{PZH}	propagation delay OE to A _n ; OE to B _n ; signal name DIR	see Figs 5 and 6	15 pF	–	4.0	8.5	1.0	10.0	1.0	11.0	ns
t _{PLZ} /t _{PHZ}	propagation delay OE to A _n ; OE to B _n ; signal name DIR			–	4.5	7.8	1.0	9.2	1.0	10.0	ns
t _{PHL} /t _{PLH}	propagation delay A _n to B _n ; B _n to A _n	see Figs 4 and 6		50 pF	–	5.0	7.5	1.0	8.5	1.0	9.5
t _{PZL} /t _{PZH}	propagation delay OE to A _n ; OE to B _n ; signal name DIR	see Figs 5 and 6	50 pF	–	5.0	10.6	1.0	12.0	1.0	13.5	ns
t _{PLZ} /t _{PHZ}	propagation delay OE to A _n ; OE to B _n ; signal name DIR			–	6.0	9.7	1.0	11.0	1.0	12.5	ns

Notes

1. Typical values at V_{CC} = 3.3 V.
2. Typical values at V_{CC} = 5.0 V.

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Type 74AHCT245

GND = 0 V; $t_r = t_f \leq 3.0$ ns.

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)						UNIT	
		WAVEFORMS	C _L	25			-40 to +85		-40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.		MAX.
V_{CC} = 4.5 to 5.5 V; note 1											
t _{PHL} /t _{PLH}	propagation delay A _n to B _n ; B _n to A _n	see Figs 4 and 6	15 pF	–	3.5	7.7	1.0	8.5	1.0	10.0	ns
t _{PZL} /t _{PZH}	propagation delay OE to A _n ; OE to B _n ; signal name DIR	see Figs 5 and 6		–	5.0	13.8	1.0	15.0	1.0	17.5	ns
t _{PLZ} /t _{PHZ}	propagation delay OE to A _n ; OE to B _n ; signal name DIR			–	5.0	14.4	1.0	15.5	1.0	18.0	ns
t _{PHL} /t _{PLH}	propagation delay A _n to B _n ; B _n to A _n	see Figs 4 and 6	50 pF	–	4.5	8.7	1.0	9.5	1.0	11.0	ns
t _{PZL} /t _{PZH}	propagation delay OE to A _n ; OE to B _n ; signal name DIR	see Figs 5 and 6		–	6.0	14.8	1.0	16.0	1.0	18.5	ns
t _{PLZ} /t _{PHZ}	propagation delay OE to A _n ; OE to B _n ; signal name DIR			–	6.0	15.4	1.0	16.5	1.0	19.5	ns

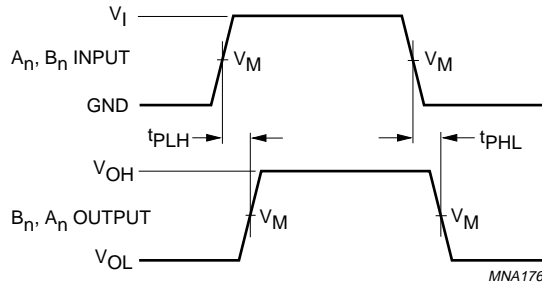
Note

1. Typical values at V_{CC} = 5.0 V.

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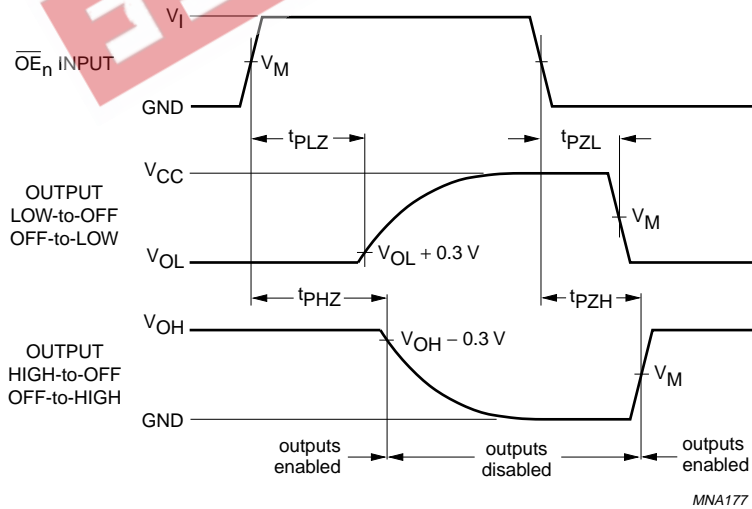
74AHC245; 74AHCT245

AC WAVEFORMS



FAMILY	V _I INPUT REQUIREMENTS	V _M INPUT	V _M OUTPUT
AHC	GND to V _{CC}	50% V _{CC}	50% V _{CC}
AHCT	GND to 3.0 V	1.5 V	50% V _{CC}

Fig.4 The input (A_n, B_n) to output (B_n, A_n) propagation delays.

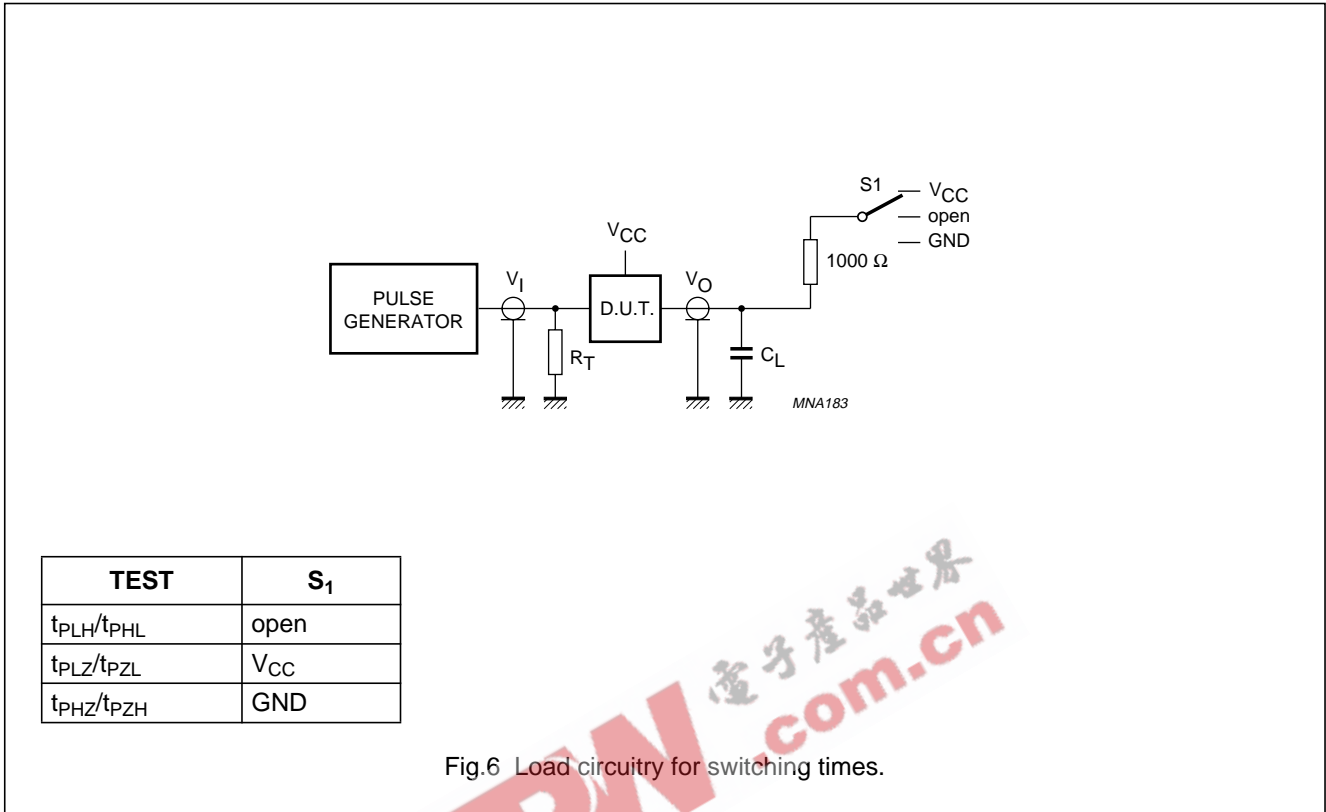


FAMILY	V _I INPUT REQUIREMENTS	V _M INPUT	V _M OUTPUT
AHC	GND to V _{CC}	50% V _{CC}	50% V _{CC}
AHCT	GND to 3.0 V	1.5 V	50% V _{CC}

Fig.5 The 3-state output enable and disable times.

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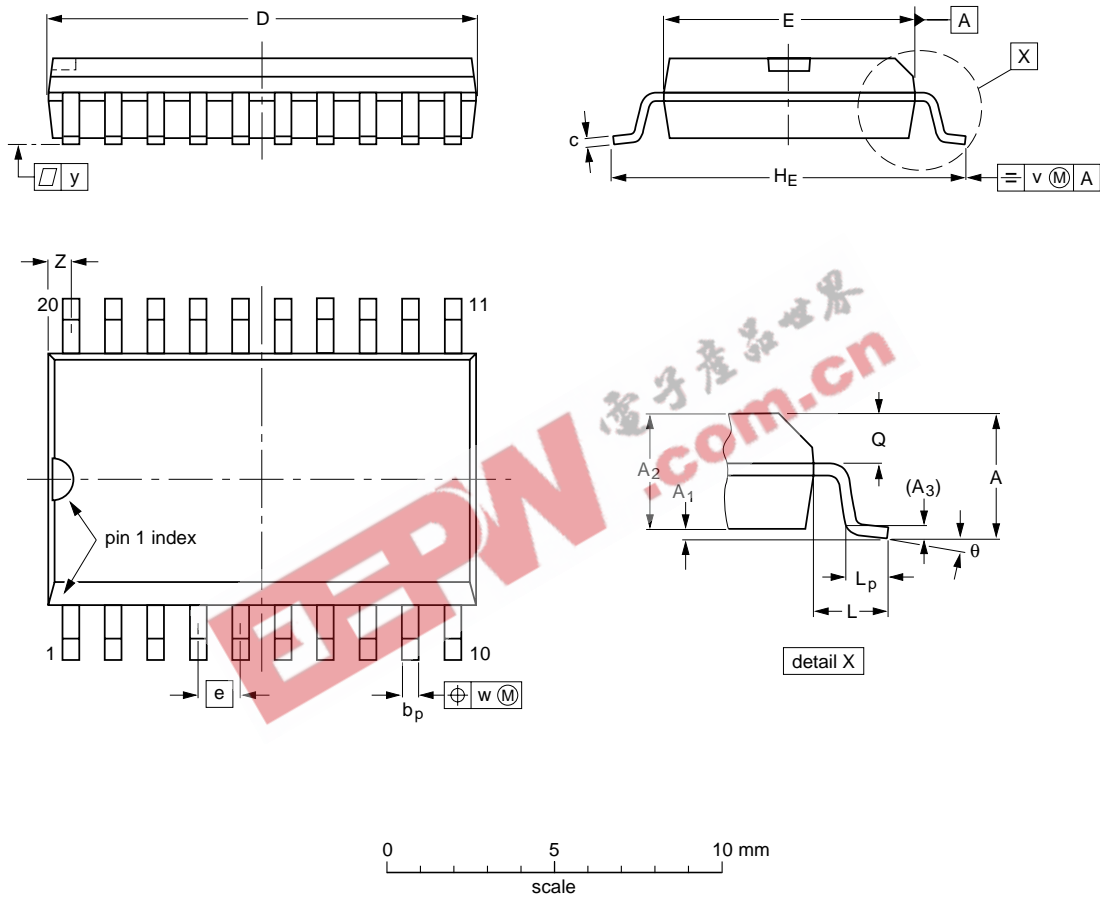
Octal bus transceiver; 3-state

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PACKAGE OUTLINES

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8° 0°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

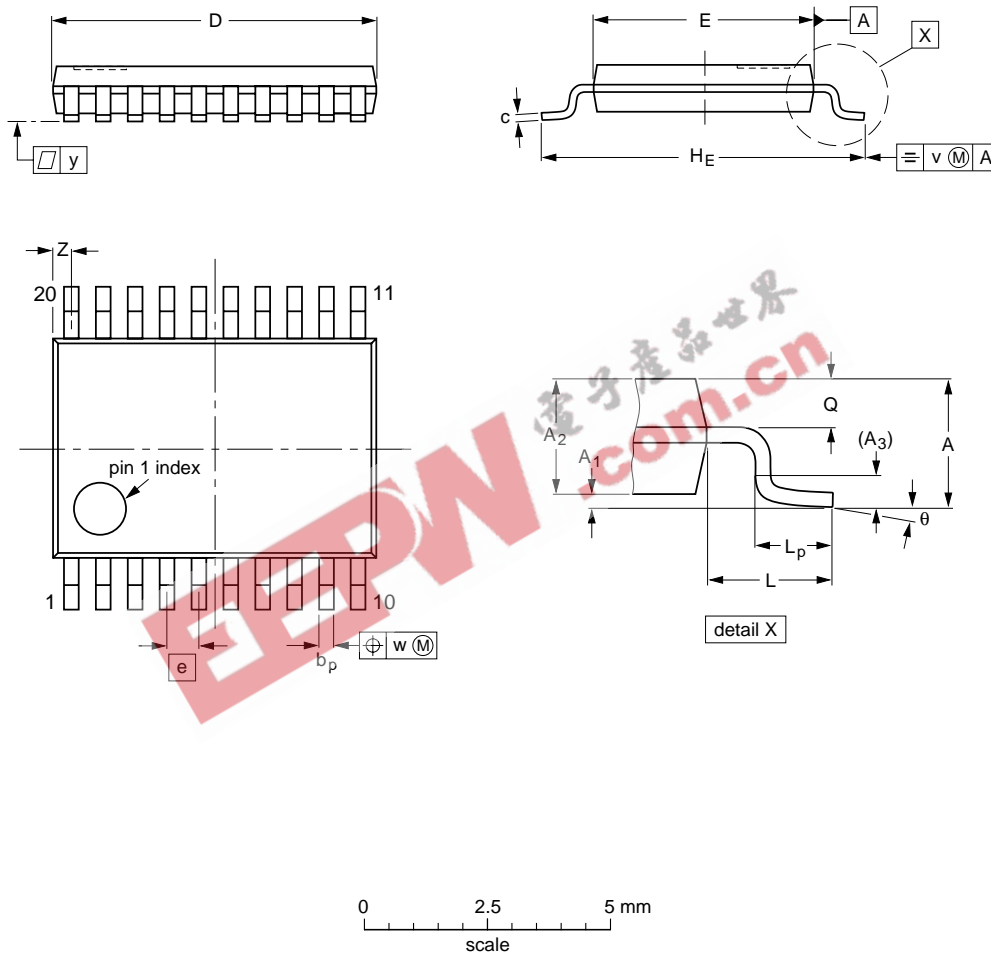
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT163-1	075E04	MS-013AC				95-01-24 97-05-22

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT360-1		MO-153AC				93-06-16 95-02-04

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SOLDERING**Introduction to soldering surface mount packages**

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 230 °C.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
 - For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.
- The footprint must incorporate solder thieves at the downstream end.
- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
	WAVE	REFLOW ⁽¹⁾
BGA, SQFP	not suitable	suitable
HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable ⁽²⁾	suitable
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable

Notes

- All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Octal bus transceiver; 3-state

74AHC245; 74AHCT245

NOTES



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